

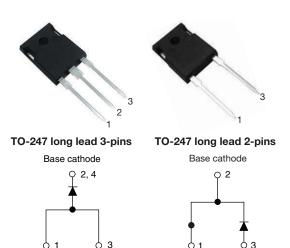
Anode

VS-APH3006L-M3

www.vishay.com

Vishay Semiconductors

## Hyperfast Rectifier, 30 A FRED Pt®



PRODUCT SUMMARY	
Package	TO-247 long lead 3 pins, TO-247 long lead 2 pins
I <sub>F(AV)</sub>	30 A
V <sub>R</sub>	600 V
V <sub>F</sub> at I <sub>F</sub>	1.4 V
t <sub>rr</sub> typ.	27 ns
T <sub>J</sub> max.	175 °C
Diode variation	Single die

Cathode

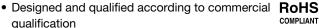
Anode

VS-EPH3006L-M3

Anode

#### **FEATURES**

- Low forward voltage drop
- Hyperfast soft recovery time
- 175 °C operating junction temperature





• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 112 °C	30	^		
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	220			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-		
Forward voltage	M	I <sub>F</sub> = 30 A	-	2.0	2.65	V	
	V <sub>F</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.4	1.8		
Reverse leakage current I <sub>R</sub>		V <sub>R</sub> = V <sub>R</sub> rated	-	0.02	30		
		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	300	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	20	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	



# VS-APH3006L-M3, VS-EPH3006L-M3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A, } dI_F/dt = 50 \text{ A/}\mu\text{s, } V_R = 30 \text{ A/}\mu\text{s}$		-	26	-	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	26	-	ns
		T <sub>J</sub> = 125 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	70	-	
Peak recovery current		T <sub>J</sub> = 25 °C		-	3.5	-	А
	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	7.6	-	
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	50	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	280	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.7	1.1	°C/W
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	5.5	-	g
Weight			-	0.2	-	OZ.
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)
Marking device		Case style TO-247 long lead 3-pins	APH3006L			
		Case style TO-247 long lead 2-pins	EPH3006L			



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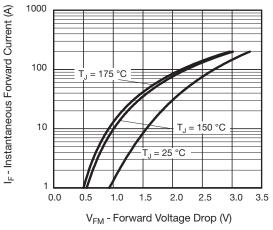


Fig. 1 - Typical Forward Voltage Drop Characteristics

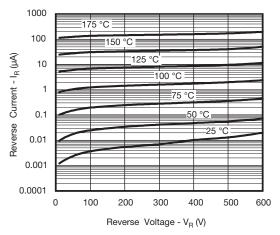


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

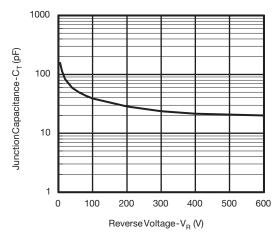


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

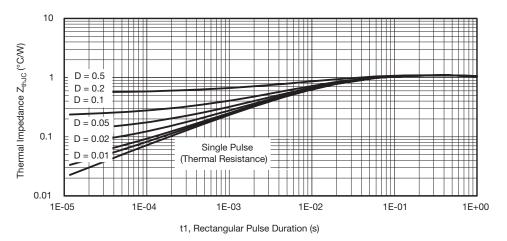


Fig. 4 - Max. Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

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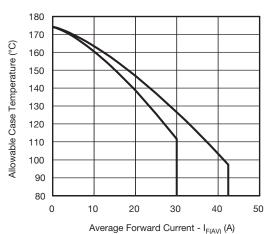


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

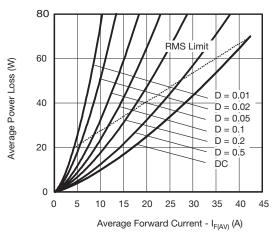


Fig. 6 - Forward Power Loss Characteristics

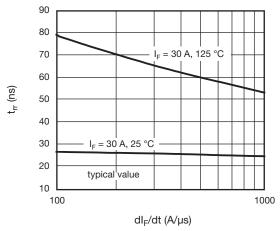


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

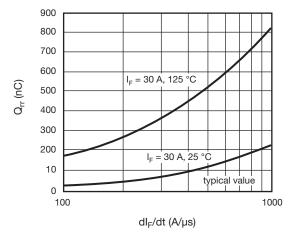
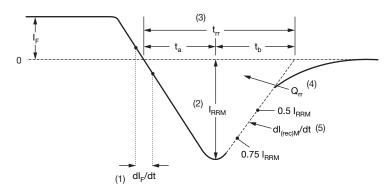


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\text{rr}}$  area under curve defined by  $\mathbf{t}_{\text{rr}}$  and  $\mathbf{I}_{\text{RRM}}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

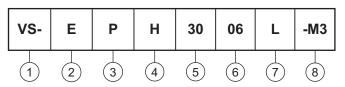
Fig. 9 - Reverse Recovery Waveform and Definitions

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### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

- • A = single diode

• E = single diode

**3** - P = TO-247

H = hyperfast recovery time

- Current code (30 = 30 A)

6 - Voltage code (06 = 600 V)

7 - L = long lead

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and termination lead (Pb)-free

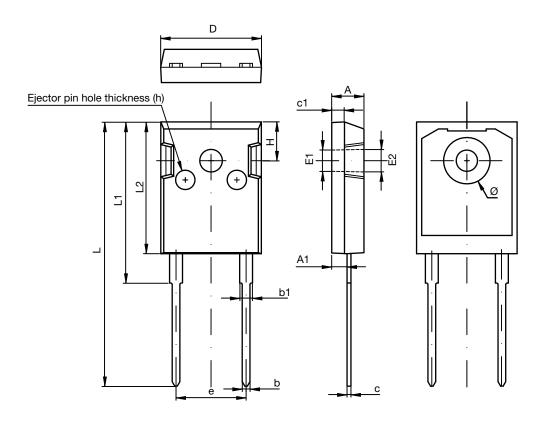
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-APH3006L-M3	30	300	Antistatic plastic tube			
VS-EPH3006L-M3	30	300	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247 3-pins LL	www.vishay.com/doc?95599		
Dimensions	TO-247 2-pins LL	www.vishay.com/doc?95598		
Part marking information	TO-247 3-pins LL	www.vishay.com/doc?95593		
	TO-247 2-pins LL	www.vishav.com/doc?95592		

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### **TO-247AD 2L**

### **DIMENSIONS** in millimeters



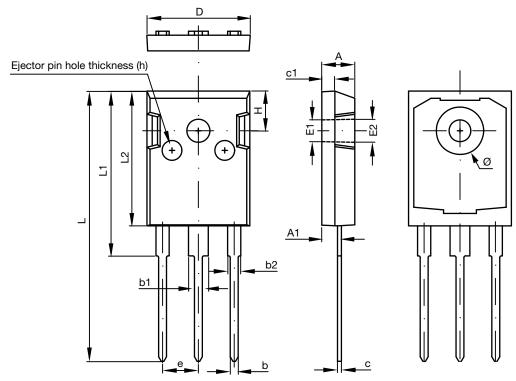
SYMBOL	DIMENSIONS I	N MILLIMETERS	DIMENSION	S IN INCHES
STINIDUL	MIN.	MAX.	MIN.	MAX.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 Ref.		0.138	Ref.
E2	3.60	00 Ref.	0.142 Ref.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Ø	7.100	7.300	0.280	0.287
е	10.900 Typ.		0.429 Typ.	
Н	5.980 Typ.		0.235	5 Тур.
h	0.000	0.300	0.000	0.012



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### **TO-247AD 3L**

### **DIMENSIONS** in millimeters



CVMDOL	DIMENSIONS	IN MILLIMETERS	DIMENSION	S IN INCHES
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	2.800	3.200	0.110	0.126
b2	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.5	3.500 Ref.		Ref.
E2	3.6	00 Ref.	0.142 Ref.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Ø	7.100	7.300	0.280	0.287
е	5.4	5.450 Typ.		Тур.
Н	5.9	5.980 Typ.		5 Тур.
h	0.000	0.300	0.000	0.012



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